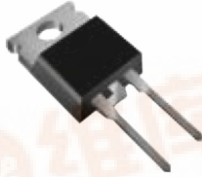
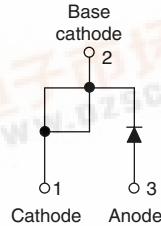




High Performance Schottky Generation 5.0, 20 A



TO-220AC



FEATURES

- 175 °C high performance Schottky diode
- Very low forward voltage drop
- Extremely low reverse leakage
- Optimized V_F vs. I_F trade off for high efficiency
- Increased ruggedness for reverse avalanche capability
- RBSOA available
- Negligible switching losses
- Submicron trench technology
- Full lead (Pb)-free and RoHS compliant devices
- Designed and qualified for industrial level



RoHS COMPLIANT

PRODUCT SUMMARY

$I_{F(AV)}$	20 A
V_R	100 V

APPLICATIONS

- High efficiency SMPS
- Automotive
- High frequency switching
- Output rectification
- Reverse battery protection
- Freewheeling
- Dc-to-dc systems
- Increased power density systems

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	20	A
V_{RRM}		100	V
V_F	20 Apk, $T_J = 125^\circ\text{C}$ (typical)	0.63	
T_J	Range	- 55 to 175	$^\circ\text{C}$

VOLTAGE RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	20TT100	UNITS
Maximum DC reverse voltage	V_R	$T_J = 25^\circ\text{C}$	100	V

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	50 % duty cycle at $T_C = 160^\circ\text{C}$, rectangular waveform	20	A
Maximum peak one cycle non-repetitive surge current	I_{FSM}	5 μs sine or 3 μs rect. pulse	900	
		10 ms sine or 6 ms rect. pulse	300	
Non-repetitive avalanche energy	E_{AS}	$T_J = 25^\circ\text{C}$, $I_{AS} = 1.5\text{ A}$, $L = 60\text{ mH}$	67.5	mJ
Repetitive avalanche current	I_{AR}	Limited by frequency of operation and time pulse duration so that $T_J < T_J\text{ max}$. I_{AS} at T_J maximum as a function of time pulse See fig. 8	I_{AS} at T_J maximum	A



20TT100



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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Forward voltage drop	$V_{FM}^{(1)}$	20 A	$T_J = 25\text{ }^\circ\text{C}$	-	0.8	V
		40 A		-	0.95	
		20 A	$T_J = 125\text{ }^\circ\text{C}$	-	0.67	
		40 A		-	0.8	
Reverse leakage current	$I_{RM}^{(1)}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_R$	-	150	μA
		$T_J = 125\text{ }^\circ\text{C}$		-	6	mA
Junction capacitance	C_T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) $25\text{ }^\circ\text{C}$		850	-	pF
Series inductance	L_S	Measured lead to lead 5 mm from package body		8.0	-	nH
Maximum voltage rate of change	dV/dt	Rated V_R		-	10 000	V/ μs

Note

(1) Pulse width < 300 μs , duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T_J, T_{Stg}		- 55 to 175	$^\circ\text{C}$
Maximum thermal resistance, junction to case	R_{thJC}	DC operation	2	$^\circ\text{C/W}$
Typical thermal resistance, case to heatsink	R_{thCS}	Mounting surface, smooth and greased	0.5	
Approximate weight			2	g
			0.07	oz.
Mounting torque	minimum		6 (5)	kgf · cm (lbf · in)
	maximum		12 (10)	
Case style			TO-220AC	
Marking device			20TT100	

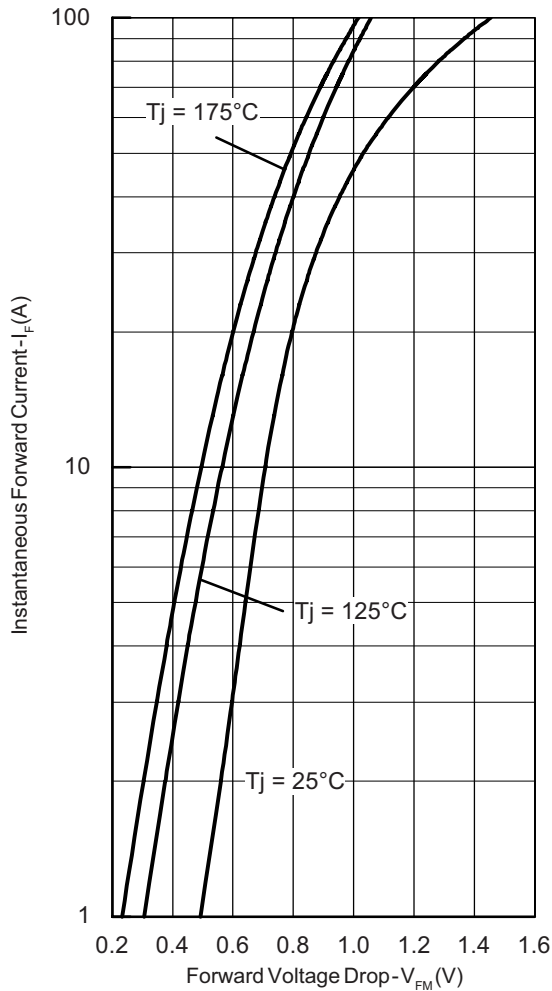


Fig. 1 - Maximum Forward Voltage Drop Characteristics

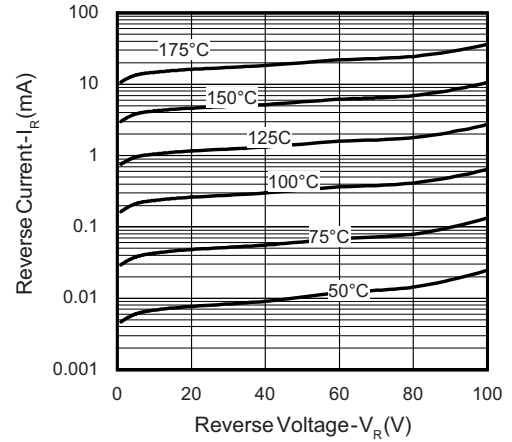


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

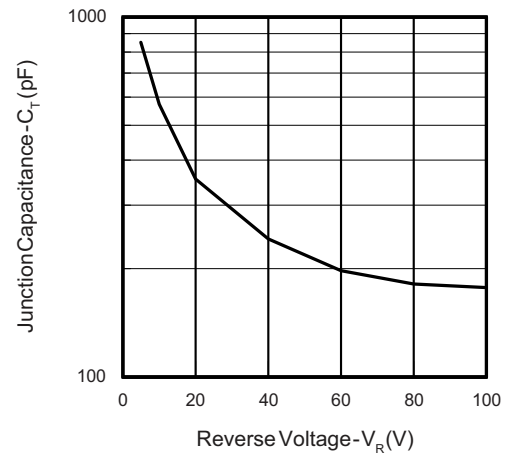


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

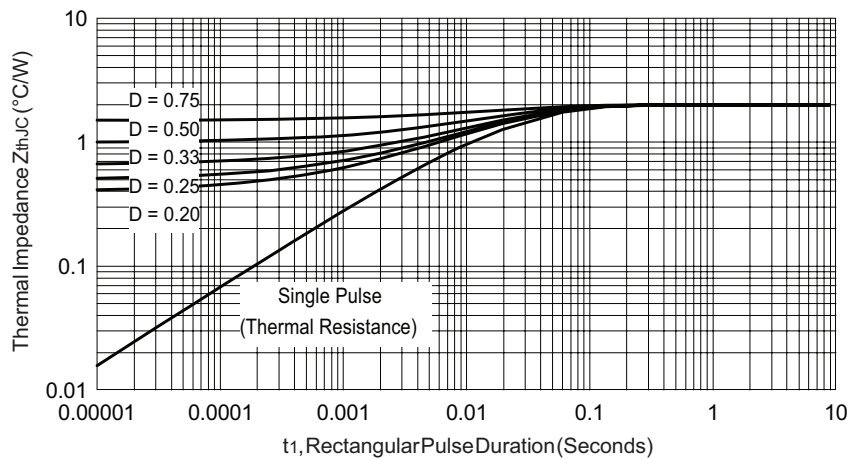


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

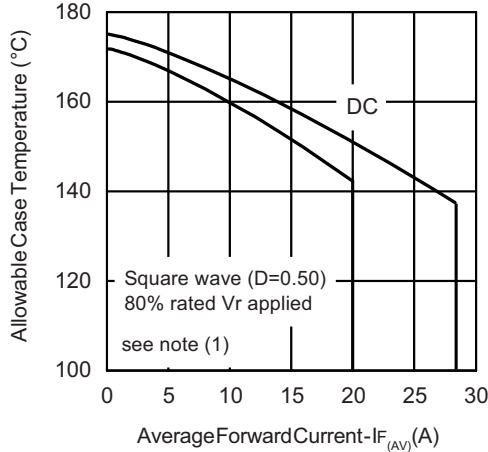


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

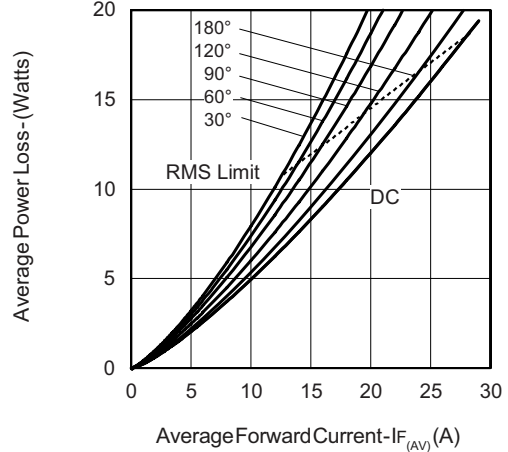


Fig. 6 - Forward Power Loss Characteristics

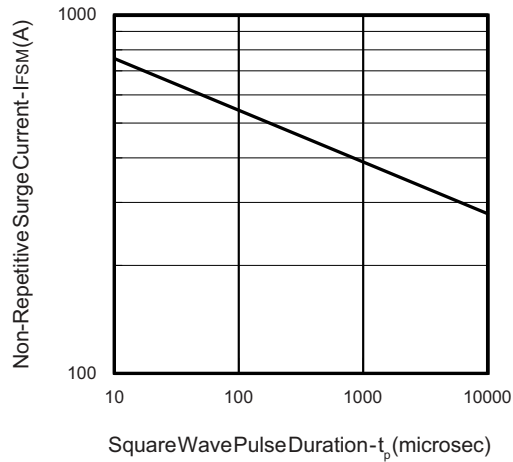


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;
- P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
- $P_{d_{REV}}$ = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80\%$ rated V_R



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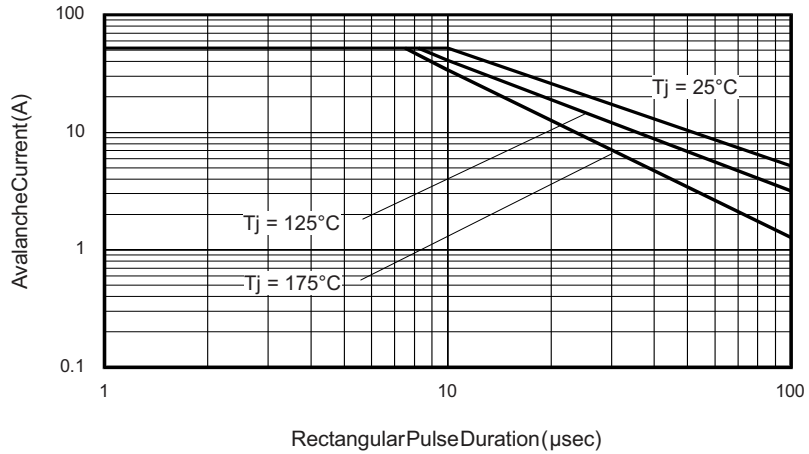


Fig. 8 - Reverse Bias Safe Operating Area (Avalanche Current vs. Rectangular Pulse Duration)

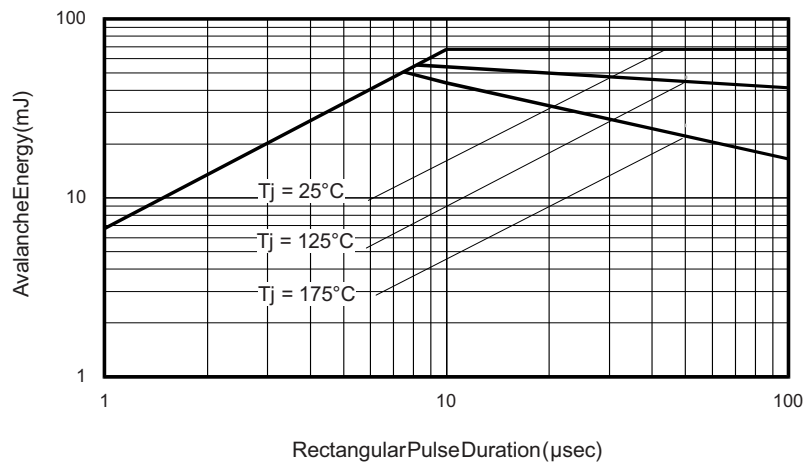


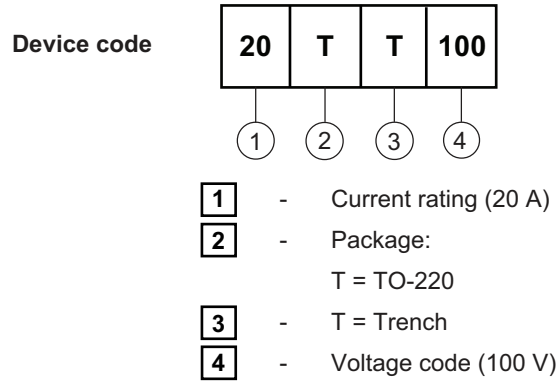
Fig. 9 - Reverse Bias Safe Operating Area (Avalanche Energy vs. Rectangular Pulse Duration)

20TT100



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ORDERING INFORMATION TABLE



Tube standard pack quantity: 50 pieces

LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95221
Part marking information	http://www.vishay.com/doc?95224
SPIICE model	http://www.vishay.com/doc?95228



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